

# Approval Sheet

|                             |                               |
|-----------------------------|-------------------------------|
| <b>Customer</b>             |                               |
| <b>Product Number</b>       | M3CW-8GPS3W0C-A               |
| <b>Module speed</b>         | PC3-12800                     |
| <b>Pin</b>                  | 240pin                        |
| <b>CI-tRCD-tRP</b>          | 11-11-11                      |
| <b>SDRAM Operating Temp</b> | -40°C ~85°C                   |
| <b>Date</b>                 | 30 <sup>th</sup> October 2014 |

**Approval by Customer**

**P/N:**

**Signature:**

**Date:**

**Sales:** \_\_\_\_\_

**Sr. Technical Manager: John Hsieh**

Rev 1.0

## 1. Features

### Key Parameter

| Industry<br>Nomenclature | Speed<br>Grade | Data Rate MT/s |      |       | tAA<br>(ns) | tRCD<br>(ns) | tRP<br>(ns) | tRC<br>(ns) |
|--------------------------|----------------|----------------|------|-------|-------------|--------------|-------------|-------------|
|                          |                | CL=7           | CL=9 | CL=11 |             |              |             |             |
| PC3-12800                | P              | 1066           | 1333 | 1600  | 13.75       | 13.75        | 13.75       | 48.75       |

- JEDEC Standard 240-pin Dual In-Line Memory Module
- Intend for PC3-12800 applications
- Inputs and Outputs are SSTL-15 compatible
- VDD=VDDQ= 1.5 Volt  $\pm$  0.075
- Bi-directional Differential Data Strobe
- DLL aligns DQ and DQS transition with CK transition
- SDRAMs have 8 internal banks for concurrent operation
- Normal and Dynamic On-Die Termination support.
- SDRAMs are 78-ball BGA Package
- Golden Connector (Au: 30u")
- 8 bit pre-fetch
- Two different termination values (Rtt\_Nom & Rtt\_WR)
- Auto & self refresh 7.8 $\mu$ s ( $T_A \leq +85^\circ\text{C}$ )
- 16/10/2 Addressing (row/column/rank)-8GB
- SDRAM operating temperature range  $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$
- Programmable Device Operation:
  - Burst Type: Sequential or Interleave
  - Device CAS# Latency: 7,9,11
  - Burst Length: switch on-the-fly: BL=8 or BC 4
- RoHS Compliant (*Section 13*)

## 2. Environmental Requirements

iDIMM are intended for use in standard office environments that have limited capacity for heating and air conditioning.

| Symbol | Parameter                                 | Rating      | Units    | Notes |
|--------|---|-------------|----------|-------|
| TOPR   | Operating Temperature (ambient)           | -40 to +85  | °C       | 1     |
| TSTG   | Storage Temperature                       | -50 to +100 | °C       |       |
| HOPR   | Operating Humidity (relative)             | 10 to 90    | %        |       |
| HSTG   | Storage Humidity (without condensation)   | 5 to 95     | %        |       |
| PBAR   | Barometric Pressure (operating & storage) | 105 to 69   | K Pascal | 1,2   |

1. The component maximum case temperature (Tcase) shall not exceed the value specified in the DDR DRAM component specification.  
 2. Up to 9850 ft.

## 3. SDRAM Parameters by device density

| RTT_Nom Setting | Parameter                           | 4Gb                 | Units  |
|-----------------|-------------------------------------|---------------------|--------|
| tRFC            | REF command ACT or REF command time | 260                 | ns     |
| tREFI           | Average periodic refresh interval   | 0°C ≤ TCASE ≤ 85°C  | 7.8 μs |
|                 |                                     | 85°C ≤ TCASE ≤ 95°C | 3.9 μs |

#### 4. Ordering Information

| W/T DDR3 UDIMM/wECC |         |           |                   |                |                |     |
|---------------------|---------|-----------|-------------------|----------------|----------------|-----|
| Part Number         | Density | Speed     | DIMM Organization | Number of DRAM | Number of rank | ECC |
| M3CW-8GPS3W0C-A     | 8GB     | PC3-12800 | 1G x72            | 18             | 2              | Y   |

## 5. Pin Configurations (Front side/Back side)

### X72 UDIMM

| Pin | Front  | Pin | Back                      | Pin | Front           | Pin | Back                      | Pin | Front     | Pin | Back                      | Pin | Front | Pin | Back                      |
|-----|--------|-----|---------------------------|-----|-----------------|-----|---------------------------|-----|-----------|-----|---------------------------|-----|-------|-----|---------------------------|
| 1   | VREFDQ | 121 | Vss                       | 31  | DQ25            | 151 | Vss                       | 61  | A2        | 181 | A1                        | 91  | DQ41  | 211 | Vss                       |
| 2   | Vss    | 122 | DQ4                       | 32  | Vss             | 152 | DM3,<br>DQS12,<br>TDQS12  | 62  | VDD       | 182 | VDD                       | 92  | Vss   | 212 | DM5,<br>DQS14,<br>TDQS14  |
| 3   | DQ0    | 123 | DQ5                       | 33  | DQS3#           | 153 | NC,<br>DQS12#,<br>TDQS12# | 63  | NC, CK1   | 183 | VDD                       | 93  | DQS5# | 213 | NC,<br>DQS14#,<br>TDQS14# |
| 4   | DQ1    | 124 | Vss                       | 34  | DQS3            | 154 | Vss                       | 64  | NC, CK1#  | 184 | CK0                       | 94  | DQS5  | 214 | Vss                       |
| 5   | Vss    | 125 | DM0,<br>DQS9,<br>TDQS9    | 35  | Vss             | 155 | DQ30                      | 65  | VDD       | 185 | CK#0                      | 95  | Vss   | 215 | DQ46                      |
| 6   | DQS0#  | 126 | NC,<br>DQS9#,<br>TDQS9#   | 36  | DQ26            | 156 | DQ31                      | 66  | VDD       | 186 | VDD                       | 96  | DQ42  | 216 | DQ47                      |
| 7   | DQS0   | 127 | Vss                       | 37  | DQ27            | 157 | Vss                       | 67  | VREFCA    | 187 | EVENT#,<br>NC             | 97  | DQ43  | 217 | Vss                       |
| 8   | Vss    | 128 | DQ6                       | 38  | Vss             | 158 | CB4,NC                    | 68  | PAR_IN,NC | 188 | A0                        | 98  | Vss   | 218 | DQ52                      |
| 9   | DQ2    | 129 | DQ7                       | 39  | CB0,NC          | 159 | CB5,NC                    | 69  | VDD       | 189 | VDD                       | 99  | DQ48  | 219 | DQ53                      |
| 10  | DQ3    | 130 | Vss                       | 40  | CB1,NC          | 160 | Vss                       | 70  | A10/AP    | 190 | BA1                       | 100 | DQ49  | 220 | Vss                       |
| 11  | Vss    | 131 | DQ12                      | 41  | Vss             | 161 | DM8,<br>DQS17,<br>TDQS17  | 71  | BA0       | 191 | VDD                       | 101 | Vss   | 221 | DM6,<br>DQS15,<br>TDQS15  |
| 12  | DQ8    | 132 | DQ13                      | 42  | DQS8#           | 162 | NC,<br>DQS17#,<br>TDQS17# | 72  | VDD       | 192 | RAS#                      | 102 | DQS6# | 222 | NC,<br>DQS15#,<br>TDQS15# |
| 13  | DQ9    | 133 | Vss                       | 43  | DQS8            | 163 | Vss                       | 73  | WE#       | 193 | S0#                       | 103 | DQS6  | 223 | Vss                       |
| 14  | Vss    | 134 | DM1,<br>DQS10,<br>TDQS10  | 44  | Vss             | 164 | CB6,NC                    | 74  | CAS#      | 194 | VDD                       | 104 | Vss   | 224 | DQ54                      |
| 15  | DQS1#  | 135 | NC,<br>DQS10#,<br>TDQS10# | 45  | CB2,NC          | 165 | CB7,NC                    | 75  | VDD       | 195 | ODT0                      | 105 | DQ50  | 225 | DQ55                      |
| 16  | DQS1   | 136 | Vss                       | 46  | CB3,NC          | 166 | Vss                       | 76  | S1#,NC    | 196 | A13                       | 106 | DQ51  | 226 | Vss                       |
| 17  | Vss    | 137 | DQ14                      | 47  | Vss             | 167 | NC                        | 77  | ODT1,NC   | 197 | VDD                       | 107 | Vss   | 227 | DQ60                      |
| 18  | DQ10   | 138 | DQ15                      | 48  | VTT,NC          | 168 | RESET#                    | 78  | VDD       | 198 | S3#,NC                    | 108 | DQ56  | 228 | DQ61                      |
| 19  | DQ11   | 139 | Vss                       | 49  | VTT,NC          | 169 | CKE1,NC                   | 79  | S2#,NC    | 199 | Vss                       | 109 | DQ57  | 229 | Vss                       |
| 20  | Vss    | 140 | DQ20                      | 50  | CKE0            | 170 | VDD                       | 80  | Vss       | 200 | DQ36                      | 110 | Vss   | 230 | DM7,<br>DQS16,<br>TDQS16  |
| 21  | DQ16   | 141 | DQ21                      | 51  | VDD             | 171 | A15,NC                    | 81  | DQ32      | 201 | DQ37                      | 111 | DQS7# | 231 | NC,<br>DQS16#,<br>TDQS16# |
| 22  | DQ17   | 142 | Vss                       | 52  | BA2             | 172 | A14                       | 82  | DQ33      | 202 | Vss                       | 112 | DQS7  | 232 | Vss                       |
| 23  | Vss    | 143 | DM2,<br>DQS11,<br>TDQS11  | 53  | ERR_Out#,<br>NC | 173 | VDD                       | 83  | Vss       | 203 | DM4,<br>DQS13,<br>TDQS13  | 113 | Vss   | 233 | DQ62                      |
| 24  | DQS2#  | 144 | NC,<br>DQS11#,<br>TDQS11# | 54  |                 | 174 | A12/BC#                   | 84  | DQS4#     | 204 | NC,<br>DQS13#,<br>TDQS13# | 114 | DQ58  | 234 | DQ63                      |
| 25  | DQS2   | 145 | Vss                       | 55  | A11             | 175 | A9                        | 85  | DQS4      | 205 | Vss                       | 115 | DQ59  | 235 | Vss                       |
| 26  | Vss    | 146 | DQ22                      | 56  | A7              | 176 | VDD                       | 86  | Vss       | 206 | DQ38                      | 116 | Vss   | 236 | VDDSPD                    |
| 27  | DQ18   | 147 | DQ23                      | 57  | VDD             | 177 | A8                        | 87  | DQ34      | 207 | DQ39                      | 117 | SA0   | 237 | SA0                       |
| 28  | DQ19   | 148 | Vss                       | 58  | A5              | 178 | A6                        | 88  | DQ35      | 208 | Vss                       | 118 | SCL   | 238 | SA1                       |
| 29  | Vss    | 149 | DQ28                      | 59  | A4              | 179 | VDD                       | 89  | Vss       | 209 | DQ44                      | 119 | SA2   | 239 | Vss                       |
| 30  | DQ24   | 150 | DQ29                      | 60  | VDD             | 180 | A3                        | 90  | DQ40      | 210 | DQ45                      | 120 | VTT   | 240 | VTT                       |

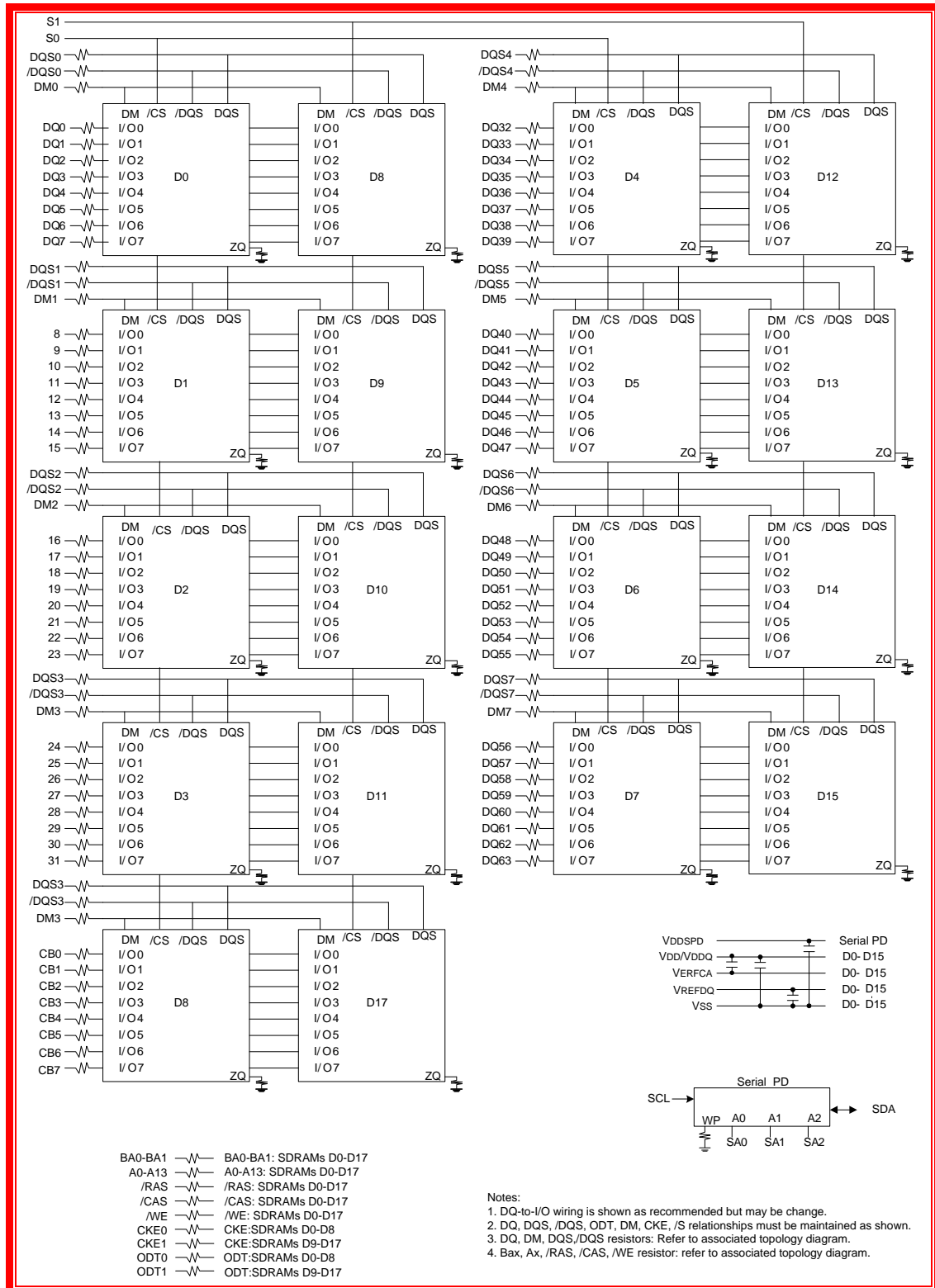
NC = No Connect, RFU = Reserved for Future Use

## 6. Architecture

### Pin Definition

| Pin Name                   | Description                 | Pin Name           | Description  |
|----------------------------|-----------------------------|--------------------|--|
| A0 - A13<br>(A14 or A15)   | SDRAM address bus           | SCL                | Serial Presence Detect Clock Input                 |
| BA0 - BA1<br>(or BA2)      | SDRAM Bank Address Inputs   | SDA                | Serial Presence Detect Data input/output           |
| /RAS                       | SDRAM row address strobe    | SA0 – SA2          | Serial Presence Detect Address Inputs              |
| /CAS                       | SDRAM column address strobe | V <sub>DD</sub>    | Power Supply                                       |
| /WE                        | SDRAM write enable          | V <sub>DDID</sub>  | V <sub>DD</sub> Identification Flag                |
| /S0 - /S1                  | DIMM Rank Select Lines      | V <sub>DDQ</sub>   | SDRAM I/O Driver power supply                      |
| CK0 – CKE1                 | SDRAM clock enable lines    | V <sub>REFDQ</sub> | SDRAM I/O Reference supply                         |
| DQ0 – DQ63                 | DIMM memory data bus        | V <sub>REFCA</sub> | SDRAM Command/address reference supply.            |
| CB0 – CB7                  | DIMM ECC check bit          | V <sub>SS</sub>    | Ground   |
| DQS0 – DQS8<br>/DQS0-/DQS8 | SDRAM data strobes          | V <sub>DDSPD</sub> | Serial EEPROM positive power supply                |
| DM0 – DM8                  | SDRAM data masks            | NC                 | Spare Pin  |
| ODT0-ODT1                  | Spare Pin                   | /Reset             | Reset enable                                       |
| CK0 – CK1<br>/CK0 - /CK1   | Differential SDRAM Clocks   | Event#             | Reserved for optional temperature-sensing hardware |
| RSVD                       | Reserved for future use.    | V <sub>TT</sub>    | SDRAM I/O termination supply.                      |

## 7. Function Block Diagram: - (8GB, 2 Ranks, 512Mx8 DDR3 SDRAMs)



## 8. SDRAM Absolute Maximum Ratings

| Symbol                             | Parameter  | Rating                   | Units     | Note |     |
|------------------------------------|--|--------------------------|-----------|------|-----|
| T <sub>OPER</sub>                  | Operation Temperature                              | Normal Operating Temp.   | -40 to 85 | °C   | 1,2 |
|                                    |  | Extended Temp.(optional) | 85 to 95  | °C   | 1,3 |
| T <sub>STG</sub>                   | Storage Temperature                                | -55 to 100               | °C        | 4,5  |     |
| V <sub>IN</sub> , V <sub>OUT</sub> | Voltage on any pins relative to V <sub>ss</sub>    | -0.4 to +1.975           | V         | 4    |     |
| V <sub>DD</sub>                    | Voltage on VDD supply relative to V <sub>ss</sub>  | -0.4 to +1.975           | V         | 4,6  |     |
| V <sub>DDQ</sub>                   | Voltage on VDDQ supply relative to V <sub>ss</sub> | -0.4 to +1.975           | V         | 4,6  |     |

**Note:**

1. Operating Temperature T<sub>OPER</sub> is the case surface temperature on the center / top side of the DRAM.

For measurement conditions, please refer to the JEDEC document JESD51-2.

2. The Normal Temperature Range specifies the temperatures where all DRAM specifications will be supported. During operation, the DRAM case temperature must be maintained between 0 to 85 °C under all operating conditions.

3. Some applications require operation of the DRAM in the Extended Temperature Range between 85 °C and 95 °C case temperature. Full specifications are supported in this range, but the following additional conditions apply:

- a) Refresh commands must be doubled in frequency, therefore reducing the Refresh interval tREFI to 3.9 μs. It is also possible to specify a component with 1X refresh (tREFI to 7.8μs) in the Extended Temperature Range. Please refer to supplier data sheet and/or the DIMM SPD for option availability.
- b) If Self-Refresh operation is required in the Extended Temperature Range, then it is mandatory to either use the Manual Self-Refresh mode with Extended Temperature Range capability (MR2 A6 =0b and MR2 A7 = 1b) or enable the optional Auto Self-Refresh mode (MR2 A6 = 1b and MR2 A7 =0b). Please refer to the supplier data sheet and/or the DIMM SPD for Auto Self-Refresh option availability, Extended Temperature Range support and tREFI requirements in the Extended Temperature Range.

4. Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is stress rating only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

5. Storage Temperature is the case surface temperature on the center/top side of the DRAM. For the measurement conditions, please refer to JESD51-2 standard.

6. VDD and VDDQ must be within 300 mV of each other at all times;and VREF must be not greater than 0.6 x VDDQ, When VDD and VDDQ are less than 500 mV; VREF may be equal to or less than 300 mV



## 9. DRAM AC & DC Operating

| Symbol                                     | Parameter  | Min                  | Typ.                          | Max                  | Units | Notes |
|--|--|----------------------|-------------------------------|----------------------|-------|-------|
| <b>Recommended DC Operating Conditions</b> |  |                      |                               |                      |       |       |
| <b>V<sub>DD</sub></b>                      | Supply Voltage   | 1.425                | 1.5                           | 1.575                | V     | 1,2   |
| <b>V<sub>DDQ</sub></b>                     | Supply Voltage   | 1.425                | 1.5                           | 1.575                | V     | 1,2   |
| <b>Single Ended AC/DC Input Levels</b>     |  |                      |                               |                      |       |       |
| <b>V<sub>IH</sub> (DC)</b>                 | DC Input High (Logic1) Voltage                               | $V_{REF} + 0.1$      | -                             | V <sub>DD</sub>      | V     | 3     |
| <b>V<sub>IL</sub> (DC)</b>                 | DC Input Low (Logic 0) Voltage                               | V <sub>SS</sub>      | -                             | $V_{REF} - 0.1$      | V     | 3     |
| <b>V<sub>IH</sub> (AC)</b>                 | AC Input High (Logic1) Voltage                               | $V_{REF} + 0.175$    | -                             | -                    | V     | 3     |
| <b>V<sub>IL</sub> (AC)</b>                 | AC Input Low (Logic 0) Voltage                               | -                    | -                             | $V_{REF} - 0.175$    | V     | 3     |
| <b>V<sub>REFDQ</sub> (DC)</b>              | Reference Voltage for DQ, DM inputs                          | 0.49V <sub>DDQ</sub> | 0.5V <sub>DDQ</sub>           | 0.51V <sub>DDQ</sub> | V     | 4,5   |
| <b>V<sub>REFCA</sub> (DC)</b>              | Reference Voltage for ADD,CMD inputs                         | 0.49V <sub>DDQ</sub> | 0.5V <sub>DDQ</sub>           | 0.51V <sub>DDQ</sub> | V     | 4,5   |
| <b>Single Ended AC/DC output Levels</b>    |  |                      |                               |                      |       |       |
| <b>V<sub>OH</sub> (DC)</b>                 | DC output high measurement level<br>(for IV curve linearity) | -                    | 0.8 x V <sub>DDQ</sub>        | -                    | V     |       |
| <b>V<sub>OM</sub> (DC)</b>                 | DC output mid measurement level<br>(for IV curve linearity)  | -                    | 0.5 x V <sub>DDQ</sub>        | -                    | V     |       |
| <b>V<sub>OL</sub> (DC)</b>                 | DC output low measurement level<br>(for IV curve linearity)  | -                    | 0.2 x V <sub>DDQ</sub>        | -                    | V     |       |
| <b>V<sub>OH</sub> (AC)</b>                 | AC output high measurement level<br>(for output SR)          | -                    | $V_{TT} + 0.1 \times V_{DDQ}$ | -                    | V     | 6     |
| <b>V<sub>OL</sub> (AC)</b>                 | AC output low measurement level<br>(for output SR)           | -                    | $V_{TT} - 0.1 \times V_{DDQ}$ | -                    | V     | 6     |

| Symbol   | Parameter   | Min  | Typ.                     | Max  | Units | Notes |
|--|---|--|--------------------------|--|-------|-------|
| <b>Differential AC/DC Input Levels</b>   |   |  |                          |  |       |       |
| <b>V<sub>IHdiff</sub></b>  | Differential Input high                                       | +0.2   | -                        | Note 9   | V     | 7     |
| <b>V<sub>ILdiff</sub></b>  | Differential Input logic Low                                  | Note 9   | -                        | -0.2   | V     | 7     |
| <b>V<sub>IHdiff(ac)</sub></b>  | Differential Input high ac                                    | 2* (V <sub>IH (AC)</sub> -<br>V <sub>REF</sub> ) | -                        | Note 9   | V     | 8     |
| <b>V<sub>ILdiff(ac)</sub></b>  | Differential Input logic Low ac                               | Note 9   | -                        | 2* (V <sub>REF</sub> -<br>V <sub>IL (AC)</sub> ) | V     | 8     |
| <b>Differential AC and DC Output Levels</b>  |   |  |                          |  |       |       |
| <b>V<sub>OHdiff(AC)</sub></b>  | AC differential output high measurement level (for output SR) | -  | + 0.2 x V <sub>DDQ</sub> | -  | V     | 10    |
| <b>V<sub>OLdiff(AC)</sub></b>  | AC differential output low measurement level (for output SR)  | -  | - 0.2 x V <sub>DDQ</sub> | -  | V     | 10    |
| <b>Note:</b>   |   |  |                          |  |       |       |
| <ol style="list-style-type: none"> <li>Under all conditions V<sub>DDQ</sub> must be less than or equal to V<sub>DD</sub>.</li> <li>V<sub>DDQ</sub> tracks with V<sub>DD</sub>. AC parameters are measured with V<sub>DD</sub> and V<sub>DDQ</sub> tied together.</li> <li>For DQ and DM, V<sub>ref</sub> = V<sub>refDQ</sub>. For input only pins except RESET#, V<sub>ref</sub> = V<sub>refCA</sub>.</li> <li>The ac peak noise on V<sub>Ref</sub> may not allow V<sub>Ref</sub> to deviate from V<sub>Ref(DC)</sub> by more than +/-1% V<sub>DD</sub> (for reference: approx. +/- 15 mV).</li> <li>For reference: approx. V<sub>DD</sub>/2 +/- 15 mV.</li> <li>The swing of ± 0.1 × V<sub>DDQ</sub> is based on approximately 50% of the static single-ended output high or low swing with a driver impedance of 40 Ω and an effective test load of 25 Ω to V<sub>TT</sub> = V<sub>DDQ</sub>/2</li> <li>Used to define a differential signal slew-rate.</li> <li>For CK - CK# use V<sub>IH</sub>/V<sub>IL</sub>(ac) of ADD/CMD and V<sub>REFCA</sub>; for DQS - DQS#, DQSL, DQSL#, DQSU, DQSU# use V<sub>IH</sub>/V<sub>IL</sub>(ac) of DQs and V<sub>REFDQ</sub>; if a reduced ac-high or ac-low level is used for a signal group, then the reduced level applies also here.</li> <li>These values are not defined, however the single-ended signals CK, CK#, DQS, DQS#, DQSL, DQSL#, DQSU, DQSU# need to be within the respective limits (V<sub>IH</sub>(dc) max, V<sub>IL</sub>(dc)min) for single- ended signals as well as the limitations for overshoot and undershoot.</li> <li>The swing of ± 0.2 × V<sub>DDQ</sub> is based on approximately 50% of the static single-ended output high or low swing with a driver impedance of 40 Ω and an effective test load of 25 Ω to V<sub>TT</sub> = V<sub>DDQ</sub>/2 at each of the differential outputs.</li> </ol> |   |  |                          |  |       |       |

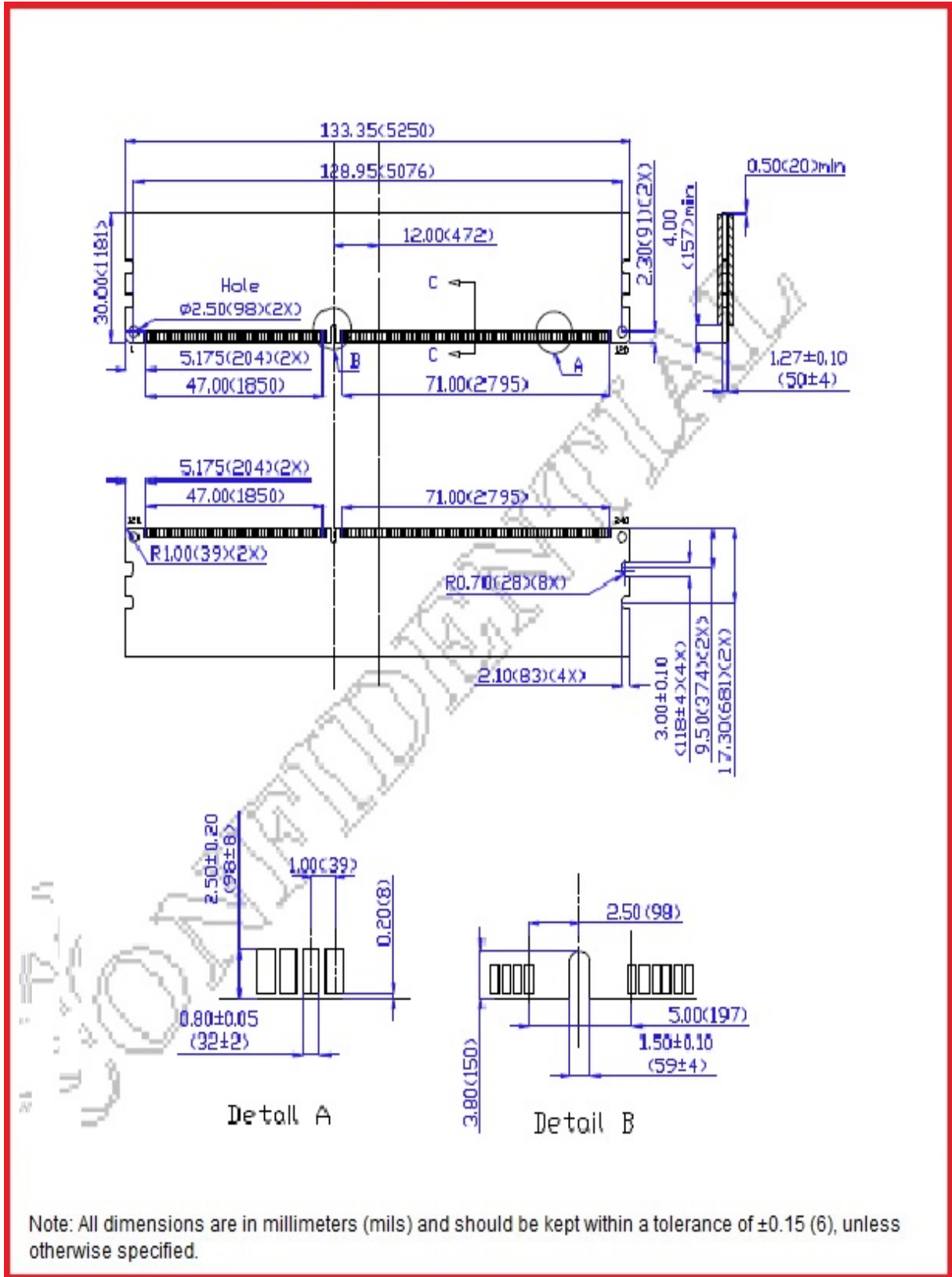
## 10. Operating, Standby, and Refresh Currents

- 8GB UDIMMw/ECC (2 Ranks, 512Mx8 DDR3 SDRAMs  $T_{CASE} = -40\text{ }^{\circ}\text{C} \sim 85\text{ }^{\circ}\text{C}$ )

| Symbol | Parameter/Condition                            | PC3-12800 | Unit |
|--------|--|-----------|------|
| I DD0  | One bank; Active - Precharge                   | 750       | mA   |
| I DD1  | One bank; Active - Read - Precharge            | 835       | mA   |
| I DD2N | Precharge Standby Current                      | 530       | mA   |
| I DD2P | Precharge Power Down Current                   | Fast      | 385  |
|        |  | Slow      | 350  |
| I DD2Q | Precharge Quiet Standby Current                | 530       | mA   |
| I DD3N | Active Standby Current                         | 615       | mA   |
| I DD3P | Active Power-Down Current                      | 440       | mA   |
| I DD4R | Operating Current Burst Read                   | 1310      | mA   |
| I DD4W | Operating Current Burst Write                  | 1350      | mA   |
| I DD5B | Burst Refresh Current                          | 1470      | mA   |
| I DD6  | Self-Refresh Current: Normal Temperature Range | 350       | mA   |
| I DD7  | Operating Bank Interleave Read Current         | 1750      | mA   |

**11. PACKAGE DIMENSION**

- (8GB, 2 Ranks, 512Mx8 DDR3 base UDIMMw/ECC)



## 12. RoHS Declaration



### Declaration of Conformity

We, InnoDisk Co., Ltd, here declare the product M3CW-8GPS3W0C-(X) complies with the requirement of RoHS directives 2002/95/EC and 2006/122/EC.

Innodisk ensures the above product meets RoHS requirements of six restricted substances. This declaration is based on vendor supplied analysis/MSDS, material certifications, and/ or 3<sup>rd</sup> party test reports of the component/ raw materials used in the manufacture of products.

| Name of hazardous substance      | Limited of RoHS ppm (mg/kg) |
|----------------------------------|-----------------------------|
| Cd                               | < 100 ppm                   |
| Pb                               | < 1000 ppm                  |
| Hg                               | < 1000 ppm                  |
| Chromium VI (Cr+6)               | < 1000 ppm                  |
| Polybromodiphenyl ether (PBDE)   | < 1000 ppm                  |
| Polybrominated Biphenyls (PBB)   | < 1000 ppm                  |
| Perfluorooctane Sulfonate (PFOS) | Not Contained               |

Date issued : 2014/01/01

Manufacturer: : InnoDisk Co., Ltd.  
 Address : 9F, No. 100, Sec.1 Xintai 5<sup>th</sup> Rd.,  
Xizhi City, Taipei 221, Taiwan

Authorized Signature :

QA Dept. Director - *Ryan Tsai*

## Revision Log

| Rev | Date                          | Modification        |
|-----|-------------------------------|---------------------|
| 0.1 | 30 <sup>th</sup> October 2014 | Preliminary Edition |
| 1.0 | 30 <sup>th</sup> October 2014 | Official released.  |